Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-027-8749

Inclosure Material:

Metal

Overall Length:

1.573 inches

Terminal Length:

0.312 inches

Overall Height:

Between 0.250 inches and 0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

170.0 collector to base voltage/static/emitter open and 170.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

16.00 amperes repetitive peak forward current blank

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Burn-in test requirements; junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

NSN 5961-01-027-8749 Transistor - Page 2 of 2

Fiig: A110a0

